## XP03390

## Silicon NPN epitaxial planar transistor (Tr1) Silicon PNP epitaxial planar transistor (Tr2)

### For digital circuits

#### ■ Features

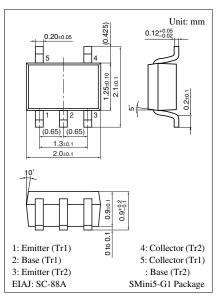
- Two elements incorporated into one package (Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

#### ■ Basic Part Number of Element

• UNR1213 (UN1213) + UNR1114 (UN1114)

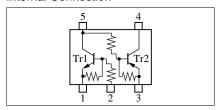
## ■ Absolute Maximum Ratings $T_a = 25$ °C

	Parameter	Symbol	Rating	Unit
Tr1	Collector to base voltage	$V_{CBO}$	50	V
	Collector to emitter voltage	$V_{CEO}$	50	V
	Collector current	$I_C$	100	mA
Tr2	Collector to base voltage	$V_{CBO}$	-50	V
	Collector to emitter voltage	$V_{CEO}$	-50	V
	Collector current	$I_C$	-100	mA
Total	Total power dissipation	$P_{T}$	150	mW
	Junction temperature	$T_{j}$	150	°C
	Storage temperature	$T_{stg}$	-55 to +150	°C



## Marking Symbol: EX

#### Internal Connection



## ■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

#### • Tr1

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector to base voltage	V <sub>CBO</sub>	$I_C = 10 \ \mu A, \ I_E = 0$	50			V
Collector to emitter voltage	V <sub>CEO</sub>	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	50			V
Collector cutoff current	I <sub>CBO</sub>	$V_{CB} = 50 \text{ V}, I_{E} = 0$			0.1	μΑ
	I <sub>CEO</sub>	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 6 \text{ V}, I_{C} = 0$			0.1	mA
DC current gain	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$	80			
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 10 \text{ mA}, I_B = 0.3 \text{ mA}$			0.25	V
High-level output voltage	V <sub>OH</sub>	$V_{CC} = 5 \text{ V}, V_{B} = 0.5 \text{ V}, R_{L} = 1 \text{ k}\Omega$	4.9			V
Low-level output voltage	V <sub>OL</sub>	$V_{CC} = 5 \text{ V}, V_B = 3.5 \text{ V}, R_L = 1 \text{ k}\Omega$			0.2	V
Input resistance	R <sub>1</sub>		-30%	47	+30%	kΩ
Resistance ratio	R <sub>1</sub> /R <sub>2</sub>		0.8	1.0	1.2	
Gain bandwidth product	$f_T$	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{MHz}$		150		MHz

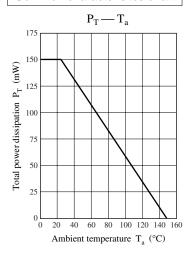
Note) The part number in the parenthesis shows conventional part number.

## $\blacksquare$ Electrical Characteristics (continued) $T_a = 25^{\circ}C \pm 3^{\circ}C$

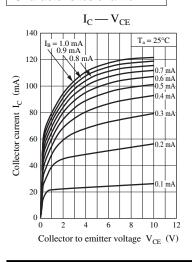
#### • Tr2

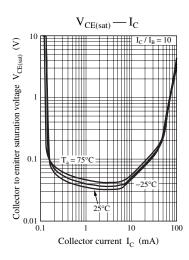
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector to base voltage	V <sub>CBO</sub>	$I_{\rm C} = -10 \; \mu \text{A}, \; I_{\rm E} = 0$	-50			V
Collector to emitter voltage	V <sub>CEO</sub>	$I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$	-50			V
Collector cutoff current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$			- 0.1	μΑ
	I <sub>CEO</sub>	$V_{CE} = -50 \text{ V}, I_{B} = 0$			- 0.5	
Emitter cutoff current	$I_{EBO}$	$V_{EB} = -6 \text{ V}, I_C = 0$			- 0.2	mA
DC current gain	h <sub>FE</sub>	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$	80			
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$			- 0.25	V
High-level output voltage	V <sub>OH</sub>	$V_{CC} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	-4.9			V
Low-level output voltage	V <sub>OL</sub>	$V_{CC} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$			- 0.2	V
Input resistance	$R_1$		-30%	10	+30%	kΩ
Resistance ratio	R <sub>1</sub> /R <sub>2</sub>		0.17	0.21	0.25	
Gain bandwidth product	$f_T$	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200\text{MHz}$		80		MHz

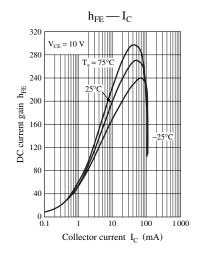
### Common characterisitcs chart



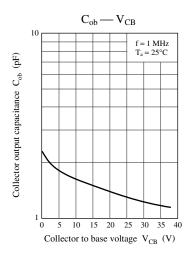
## Characterisitcs chart of Tr1

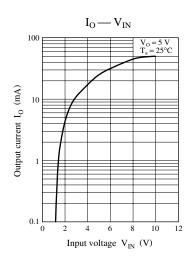


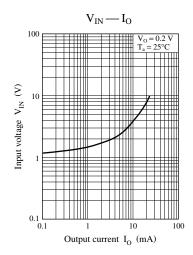




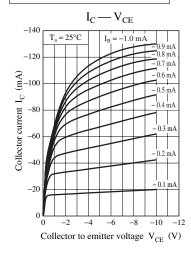
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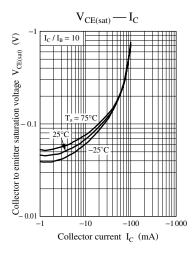


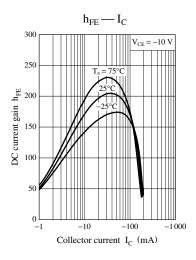


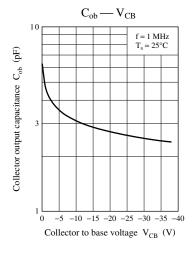


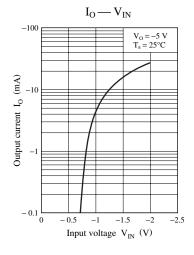
#### Characterisitcs chart of Tr2

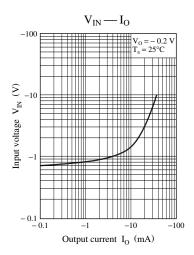












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